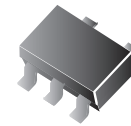


RoHS Device
Halogen Free

Features

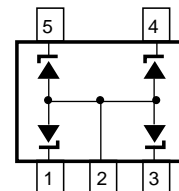
- Solid-state silicon-avalanche technology
- 30 Watts Peak Pulse Power per Line ($t_p=8/20\mu s$)
- Low operating and clamping voltages
- Up to Four (4) Lines of Protection
- Working Voltages: 5 V
- Low Leakage Current
- ESD protection >20 kV
- IEC 61000-4-2; level 4 (ESD); 15 kV (air) or 8 kV (contact).



SOT-553

Mechanical Characteristics

- SOT-553 package
- Molding compound flammability rating:
UL 94V-0
- Marking: Marking Code
- Packaging: Tape and Reel



Applications

- Cellular Handsets & Accessories
- Personal Digital Assistants (PDAs)
- Notebooks & Handhelds
- Portable Instrumentation
- Digital Cameras
- MP3 Player

PINNING

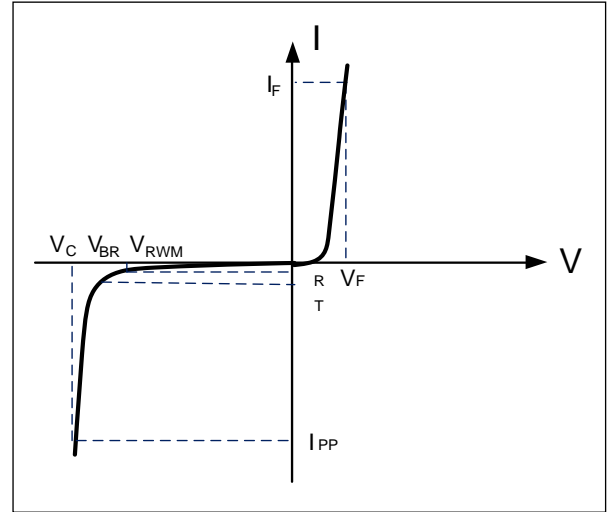
PIN	DESCRIPTION
1	cathode 1
2	common anode
3	cathode 2
4	cathode 3
5	cathode 4

Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ($t_p=8/20\mu s$)	P_{PP}	30	Watts
Peak Forward Voltage ($I_F=1A, t_p=8/20\mu s$)	V_{FP}	1.5	V
Operating Temperature	T_J	-55 to + 125	°C
Storage Temperature	T_{STG}	-55 to +150	°C

Electrical Parameters (T=25°C)

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_F	Forward Current
V_F	Forward Voltage @ I_F



Electrical Characteristics

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand Off Voltage	V_{RWM}				5.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1mA$	6.0			V
Reverse Leakage Current	I_R	$V_{RWM}=5V, T=25^\circ C$			1	μA
Peak Pulse Current	I_{PP}	$t_p=8/20\mu s$			2	A
Clamping Voltage	V_C	$I_{PP}=2A, t_p=8/20\mu s$		11		V
Junction Capacitance	C_j	Between I/O pins and Ground $V_R = 0V, f = 1MHz$		6.5		pF

Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

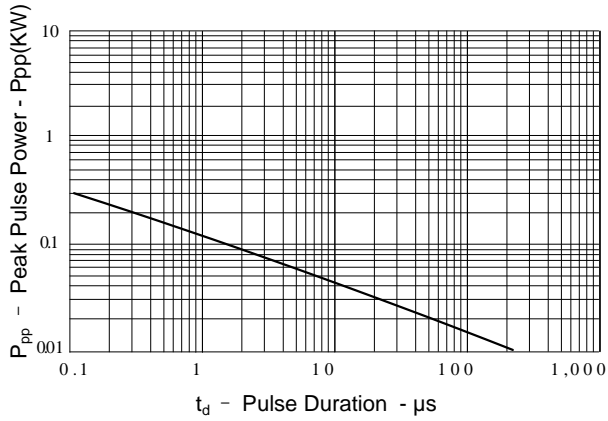


Figure 2: Power Derating Curve

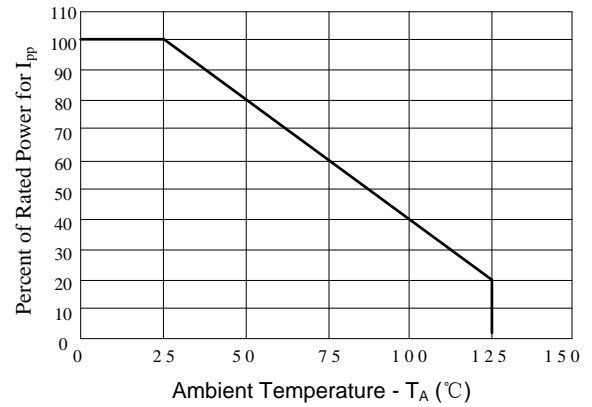


Figure 3: NZQA6V8AXV5 Insertion Loss

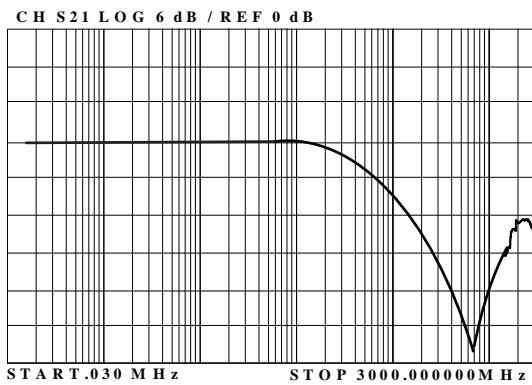


Figure 4: Normalized Junction Capacitance vs. Reverse Voltage

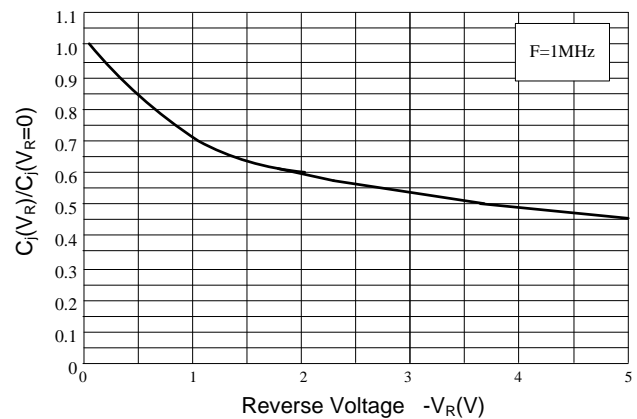
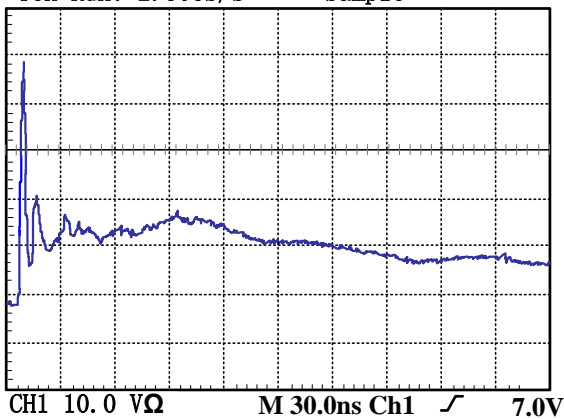


Figure 5: ESD Clamping (8kV Contact per IEC 61000-4-2)

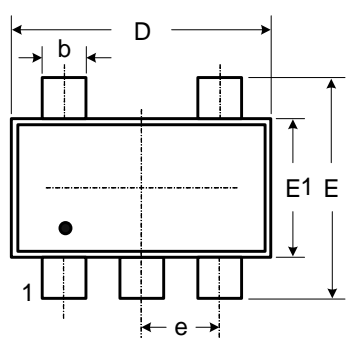
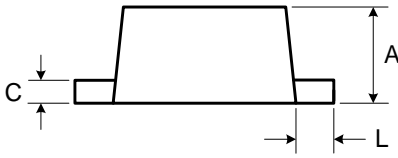
Tek Run: 2.50GS/s

Sample

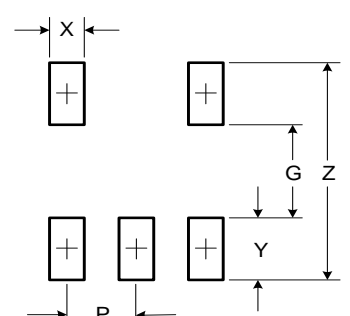


Outline Drawing–SOT-553

PACKAGE OUTLINE		DIMENSIONS			
SYMBOL	INCHES		MILLIMETER		
	MIN	MAX	MIN	MAX	
A	0.021	0.024	0.525	0.600	
b	0.007	0.011	0.170	0.270	
C	0.004	0.006	0.090	0.160	
D	0.059	0.067	1.500	1.700	
E	0.059	0.067	1.500	1.700	
E1	0.043	0.051	1.100	1.300	
e	0.018	0.022	0.450	0.550	
L	0.004	0.012	0.100	0.300	

DIMENSIONS		
DIM	INCHES	MILLIMETERS
Z	0.0708	1.80
G	0.0354	0.90
P	0.0197 TYP	0.50 TYP
X	0.0118	0.3
Y	0.0177	0.45



Notes

1. Dimensioning and tolerances per ANSI Y14.5M, 1985.
2. Controlling Dimension: Inches
3. Dimensions are exclusive of mold flash and metal burrs.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [ESD Suppressors / TVS Diodes](#) category:

Click to view products by [Yenji](#) manufacturer:

Other Similar products are found below :

[NTE4902](#) [P4SMAJ15A](#) [P4SMAJ26A](#) [SMAJ400CA-TP](#) [TGL34-47CA](#) [ESDAULC45-1BF4](#) [SM1605E3/TR13](#) [SMF20A-TP](#) [P4SMAJ12A](#)
[CPDUR24V-HF](#) [CPDQC5V0USP-HF](#) [CPDQC5V0-HF](#) [MPLAD30KP45CAE3](#) [MMBZ27VCLQ-7-F](#) [MMAD1108/TR13](#) [MPLAD30KP24A](#)
[ACPDQC5V0R-HF](#) [DFLT170A-7](#) [NTE4900](#) [NTE4926](#) [NTE4938](#) [SMF22A-TP](#) [SMF12A-TP](#) [SLVU2.8-TP](#) [SMLJ6.5CA-TP](#) [SMAJ6.5CA-](#)
[TP](#) [MMAD1108E3/TR13](#) [D5V0M1U2LP3-7](#) [SMAJ400A-TP](#) [AOZ8811DT-03](#) [AOZ8831DI-05](#) [AOZ8831DT-03](#) [SMAJ188CA](#) [3SMC33CA](#)
[BK](#) [CPDQC3V3C-HF](#) [CPDQC12VE-HF](#) [MPLAD30KP170CA](#) [82357120100](#) [5.0SMLJ15CA-TP](#) [5KP18A-TP](#) [P6KE8.2A-TP](#)
[MPLAD30KP43CAE3](#) [SMAJ43A-TP](#) [D5V0F6U8LP33-7](#) [TVS5501V10MUT5G](#) [5.0SMLJ24CA-TP](#) [SMAJ110CA-TP](#) [MPLAD15KP75CAE3](#)
[MMAD1103e3/TR13](#) [DFLT40AQ-7](#)